

N-Channel 60-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

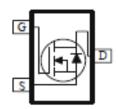
Typical Applications:

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY					
Vos (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)			
60	92 @ V _{GS} = 10V	3.1			
60	107 @ V _{GS} = 4.5V	2.9			







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)						
Parameter			Symbol	Limit	Units	
Drain-Source Voltage		V_{DS}	60	V		
Gate-Source Voltage				±20	V	
Continuos Durin Communia		=25°C	ı	3.1		
Continuous Drain Current ^a	T⊿	=70°C	I _D	2.5	Α	
Pulsed Drain Current ^b	I _{DM}	15				
Continuous Source Current (Diode Conduction) ^a	Is	1.9	Α			
Down Dissipation a		=25°C	P _D	1.3	W	
Power Dissipation ^a	T⊿	=70°C	ı D	0.8	٧٧	
Operating Junction and Storage Temperature Range				-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	100	°C/W	
Maximum Junction-to-Ambient	Steady State	I V ₀ JA	166	C/VV	

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

MI2358N

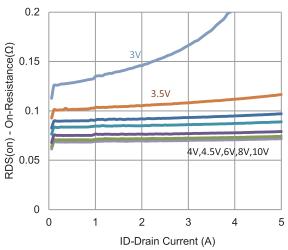
Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
	DSS	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25		
On-State Drain Current a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	5			Α	
Danie Course On Bosistanos a	r	$V_{GS} = 10 \text{ V}, I_D = 2.5 \text{ A}$			92	mΩ	
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 2 \text{ A}$			107		
Forward Transconductance a	g_{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 2.5 \text{ A}$		10		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 1 A, V _{GS} = 0 V		0.74		V	
		Dynamic ^b					
Total Gate Charge	Q_g	$V_{DS} = 30 \text{ V}, V_{GS} = 4.5 \text{ V},$		4		nC	
Gate-Source Charge	Q_{gs}	$I_{D} = 2.5 \text{ A}$		1.0			
Gate-Drain Charge	Q_{gd}	ID - 2.0 A		1.7			
Turn-On Delay Time	t _{d(on)}	$V_{DS} = 30 \text{ V}, R_{L} = 12 \Omega,$		3			
Rise Time	t _r	$I_{DS} = 30 \text{ V}, R_{L} = 12 \Omega,$ $I_{D} = 2.5 \text{ A},$		6		ns	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		17			
Fall Time	t _f	VGEN - 10 V, NGEN - 0 22		5			
Input Capacitance	C _{iss}			330		pF	
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		31			
Reverse Transfer Capacitance	C _{rss}			27			

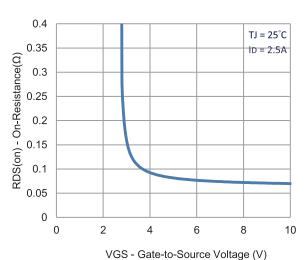
Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

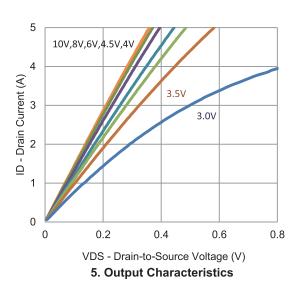
Typical Electrical Characteristics

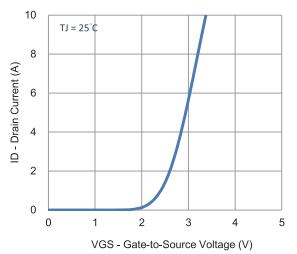


1. On-Resistance vs. Drain Current

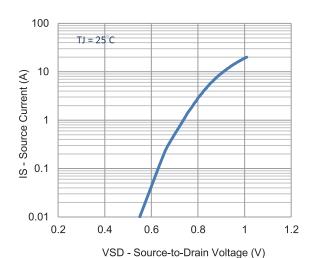


3. On-Resistance vs. Gate-to-Source Voltage

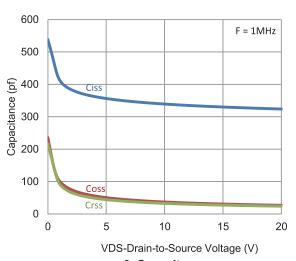




2. Transfer Characteristics

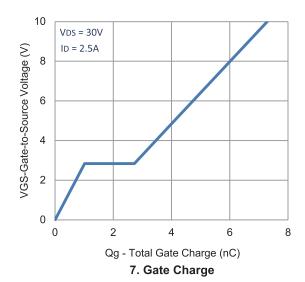


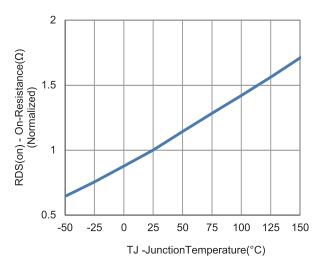
4. Drain-to-Source Forward Voltage



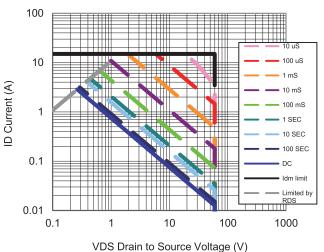
6. Capacitance

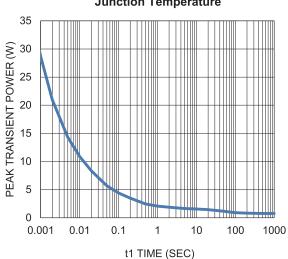






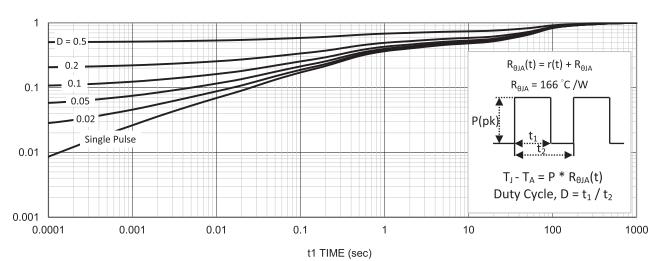
8. Normalized On-Resistance Vs Junction Temperature





9. Safe Operating Area

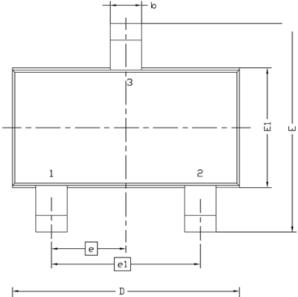
10. Single Pulse Maximum Power Dissipation



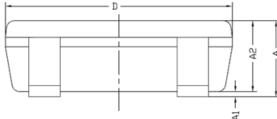
11. Normalized Thermal Transient Junction to Ambient

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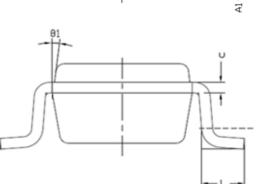
Package Information

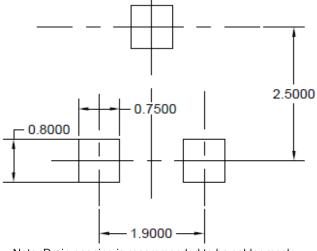


Symbol	MILLIMETERS		
Syllibol	MIN	MAX	
Α	0.8	1.2	
A1	0	0.1	
A2	0.7	1.1	
b	0.3	0.5	
С	0.1	0.2	
D	2.7	3.1	
Е	2.6	3	
E1	1.4	1.8	
е	0.95 BSC		
e1	1.9 BSC		
Ĺ	0.3	0.6	
θ1	7° NOM		



Recommended Pad Layout





Note: Drain opening is recommended to be solder mask defined in a copper fill for improved thermal performance

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